

	Type	L #	Hits	Search Text	DBs	Time Stamp	Comments	Error or Defini tion	Errors
1	BRS	L1	357	etch\$3 same endpoint same ("SiO.sub.2" or "gate electrode" or "silicon dioxide")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/12/08 10:39			
2	BRS	L2	32644549	1and @pd<="20030929"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/12/08 09:49			
3	BRS	L3	239	1 and @pd<="20030929"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/12/08 09:51			
4	BRS	L4	71	etch\$3 same endpoint same ("SiO.sub.2" or "gate electrode" or "silicon dioxide") same (wavelength or light or radiation)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/12/08 10:37			
5	BRS	L5	46	4 and @pd<="20030929"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/12/08 09:51			
6	BRS	L6	0	etch\$3 same endpoint same ("SiO.sub.2" same "gate electrode" same function) same (wavelength or light or radiation)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/12/08 10:38			
7	BRS	L7	0	etch\$3 same endpoint same ("silicon dioxide" same "gate electrode" same function) same (wavelength or light or radiation)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/12/08 10:38			
8	BRS	L8	0	etch\$3 same endpoint same ("silicon oxide" same "gate electrode" same function) same (wavelength or light or radiation)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/12/08 10:38			

9	BRS	L9	0	etch\$3 same endpoint same ("silicon oxide" same "gate electrode" same function)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/12/08 10:39			
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	Type	L #	Hits	Search Text	DBs	Time Stamp	Comments	Error or Defini tion	Errors
10	BRS	L10	1098	("silicon oxide" same "gate electrode" same function)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/12/08 10:39			
11	BRS	L11	0	10 same endpoint	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/12/08 10:39			
12	BRS	L12	9	10 and endpoint	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2005/12/08 10:39			